

Form PTO-1449

INFORMATION DISCLOSURE CITATION
IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional)

05-022-con/Tank-90can

Application Number

10/656613

Applicant

JOSEPH A. JOHNSON et al.

Filing Date

SEPT. 4, 2003

Group Art Unit

U. S. PATENT DOCUMENTS

| EXAMINER INITIAL | DOCUMENT NUMBER | DATE | NAME | CLASS | SUBCLASS | FILED DATE IF APPROPRIATE |
|---------------------|-----------------|------------|------------------|-------|----------|------------------------------|
| ZZ | 5488232 | 01-30-1996 | Glass et al. | | | |
| ZZ | 6117751 | 09-12-2000 | Schoerner et al. | | | |
| ZZ | 6426968 | 07-30-2002 | Strife et al. | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| | | | | | | |

FOREIGN PATENT DOCUMENTS

| | DOCUMENT NUMBER | DATE | COUNTRY | CLASS | SUBCLASS | Translation | |
|--|-----------------|------|---------|-------|----------|-------------|----|
| | | | | | | YES | NO |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

| | |
|----|--|
| ZZ | Hirofuki Nagasawa, Kuniaki Yagi, Takamitsu Kawahara and Naoki Hatta; "3C-SiC Monocrystals Grown on Undulant Si(001) Substrates" Pg. 47450; Material Research Society Vol. 742 © 2002 |
| ZZ | Zhiyun Cheng et al.; "Relaxed Silicon-Germanium On Insulator (SGOI); Material Research Society Symp. Proc. Vol. 686; 2002 Pg. 21-26 |

EXAMINER

Kevin Quinto

DATE CONSIDERED

9/18/04

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.